

FULLY INTEGRATED POWER SUPPLY **FIPS**TM

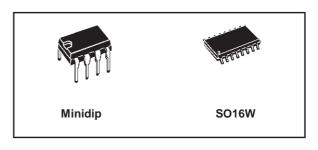
PRODUCT PREVIEW

Features

- WIDE-RANGE MAINS OPERATION
- "ON-CHIP" 700V BVDSS POWER MOS
- 65kHz INTERNAL OSCILLATOR
- 2.5V ±2% INTERNAL REFERENCE
- STANDBY MODE FOR HIGH EFFICIENCY AT LIGHT LOAD
- OVERCURRENT AND LATCHED OVERVOL-TAGE PROTECTION
- NON DISSIPATIVE BUILT-IN START-UP CIR-CUIT
- ON-CHIP SOFT START AND THERMAL SHUTDOWN

Main Applications

- WALL PLUG POWER SUPPLY UP TO 15W
- AC-DC ADAPTORS
- AUXILIARY POWER SUPPLY:
 - MONITORS (BLUE ANGEL)
 - DESKTOPS/SERVERS
 - FAX, TV, LASER PRINTERS
 - HOME APPLIANCES/LIGHTING
- LINE CARD, DC-DC CONVERTERS



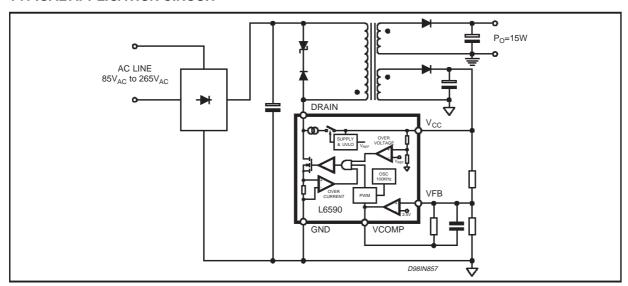
DESCRIPTION

The L6590 is a monolithic switching regulator designed in BCD OFF-LINE technology, able to operate with wide range input voltage and delivering an output power up to 13W. The internal switch is implemented by a lateral high voltage power Mosfet with an Rdson of 13Ω and a BVDss of 700V. The internal fixed oscillator frequency, non dissipative start up and the internal soft start system allow to minimize the components count. A 2.5V+/-2% internal reference in addition to a high gain error amplifier make the device suitable for low cost applications with primary control.

Internal protections like cycle by cycle current limiting, output overvoltage protection and thermal shutdown generate a 'robust' design solution.

The device automatically reduces the frequency from 65KHz to 22KHz under light load conditions improving the efficiency.

TYPICAL APPLICATION CIRCUIT

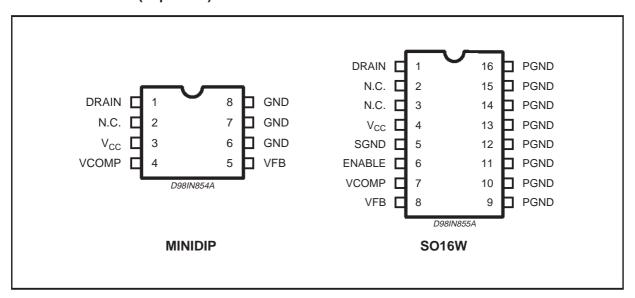


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ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{ds}	Drain Source Voltage	700	V
I _d	Drain Current	0.7	Α
V _{cc}	Supply Voltage	18	V
	Error Amplifier Output Sink Current	3	mA
P _{tot}	Power Dissipation at T _{amb} < 50°C (Minidip)	1	W
T _i	Junction Operating Temperature Range	-40 to 150	°C
T _{stg}	Storage Temperature	-40 to 150	°C

PINS CONNECTION (Top views)



THERMAL DATA

Symbol	Parameter	Minidip	SO16W	Unit
R _{th j-amb}	Thermal Resistance Junction to Ambient Free Air	60	-	°C/W
R _{th j-amb}	Thermal Resistance Junction to Ambient (*)	35 to 60	35 to 60	°C/W

^(*) Value depending from PCB copper areas and thikness.

ELECTRICAL CHARACTERISTICS ($T_j = 0$ to $105\,^{\circ}\text{C}$, $V_{cc} = 10\text{V}$) **Power Section**

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
BV _{dss}	Drain Source Voltage	$I_d = 500\mu A$	700			V
I _{dss}	Off State Drain Current	V _{ds} = 560V			500	μΑ
R _{dson}	Drain Source on state	I _d = 25mA; Tj = 25°C		13	17	Ω
	Resistance	Tj = 125°C	·	26	35	Ω

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ELECTRICAL CHARACTERISTICS (continued)

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
Error Amp	Section					
V _{fb}	Input Voltage	Tj = 25°C	2.45	2.5	2.55	V
V ID	mput voltage	Tj = 125°C	2.43	2.5	2.57	V
I _b	Input Bias Current	, , ,=0 0		-0.3	-1	μA
	Avol		60	0.0	<u> </u>	dΒ
В	Unity Gain Bandwidth		0.7	1		MHz
SVR	Supply Voltage Rejection			70		dB
I _{source}	Output Source Current	Vcomp = 3.5V	0.5	1		mA
V _{oh}	V _{out} High	$I_{\text{source}} = 0.5 \text{mA} V_{\text{fb}} = 2 \text{V}$	3.8	4.5		V
V _{ol}	V _{out} Low	$I_{sink} = 1 \text{mA} V_{fb} = 3 \text{V}$			1.0	V
Oscillator (•	- Colline				
F _{osc}	Oscillator Frequency	Tj = 25°C	58	65	72	KHz
- 030			56	65	74	KHz
Dmin	Min. Duty Cycle	Vcomp = 1V		- 50	0	%
Dmax	Max. Duty Cycle	100mp - 11	66	70	74	%
	eration Section		00	10	74	70
	Operating Supply Current	I		6	8	mA
I _{op} I _{psc}	Peak Start up Current	V _{cc} = 0V	5	10	15	mA
V _z	Zener Voltage	V cc = 0 V	17	17.5	18	V
V _{ddon}	Start Threshold Voltage		14	14.5	15	V
V _{ddon} V _{ddoff}	Min Operating Voltage After		7	7.5	8	V
v ddoff	Turn on			7.5		V
Soft Start						
V _{ccss}	Soft Start Threshold Voltage		12	12.5	13	V
Circuit Pro	tections					
I _{lim}	Pulse by Pulse Current Limit	dl/dt = 0.2A/μs	500	625	700	mA
OVP	Over Voltage Protection	, ·	15	15.5	16	V
t _m	Internal Masking Time			120		ns
Stand by S						
I _{pksb}	Current Threshold for Stand-By Operation	Transition from 65KHz to 22KHz		70		mA
F _{stb}	Stand by Frequency	Tj = 25°C	19	23	27	KHz
I _{pknor}	Current Threshold for Normal Operation	Transition from 22KHz to 65KHz		170		mA
	Stand by current	f _{SW} = fstand-by		5	7.5	mA
PN/OFF/BF	ROWN-OUT	,	<u> </u>	•	-	
V _{th on}	Threshold Voltage (Device on)		2.425	2.5	2.575	V
I _{Hyst}	Source Current	V _{pin} = 3V	30	50	70	μА
I _{off}	Supply Current in Off Condition	$V_{pin} = 2V$		0.5		mΑ
Ι _p	Source Current	$V_{pin} = 2V$		5		mA
V _{CL}	On/Off Clamp Pull-Up Voltage	$I_{\text{sink}} = 0.5 \text{mA}$	5	5.5	6	V
	SHUTDOWN (*)	I ISINK - O.OITIA] J	0.0	<u> </u>	ı v
THERWAL	1 ''	Ι	450	105		۰۰
	Thermal Shutdown		150	165		°C
	Hysteresis	l		40		°C

^(*) Parameter not tested in production.



APPLICATION EXAMPLES

Figure 1. AC-DC Adaptor, Auxiliary P.S. (Isolated bias winding feedback)

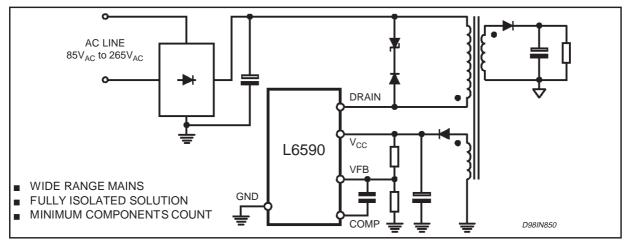


Figure 2. High Performance AC-DC Converter. (Secondary referenced optcoupler feedback)

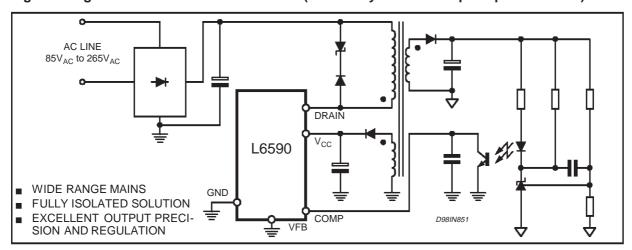
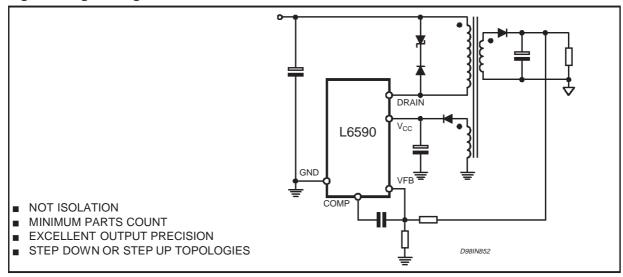


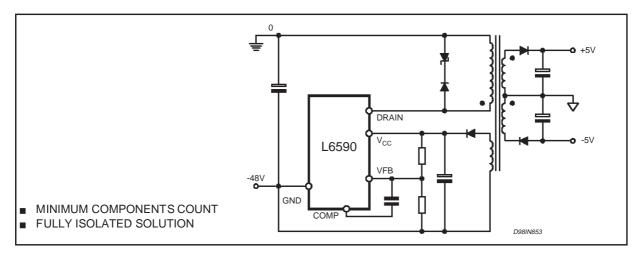
Figure 3. High Voltage DC-DC Converter.



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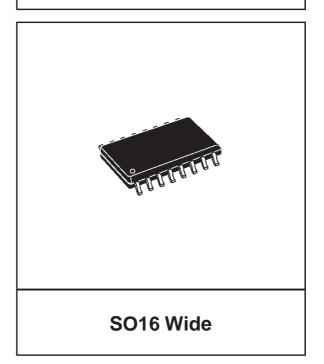
APPLICATION EXAMPLE (continued)

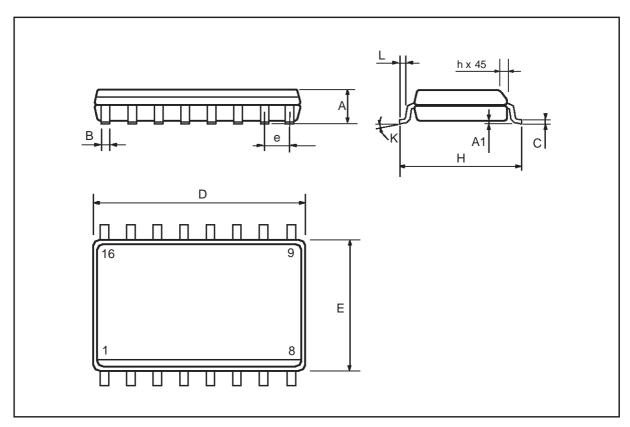
Figure 4. Line Card Application. (Isolated bias winding feedback)



DIM.	mm			inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А	2.35		2.65	0.093		0.104	
A1	0.1		0.3	0.004		0.012	
В	0.33		0.51	0.013		0.020	
С	0.23		0.32	0.009		0.013	
D	10.1		10.5	0.398		0.413	
Е	7.4		7.6	0.291		0.299	
е		1.27			0.050		
Н	10		10.65	0.394		0.419	
h	0.25		0.75	0.010		0.030	
L	0.4		1.27	0.016		0.050	
K	0° (min.)8° (max.)						

OUTLINE AND MECHANICAL DATA

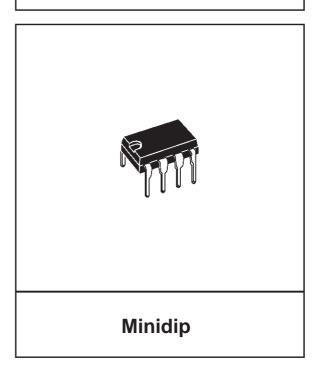


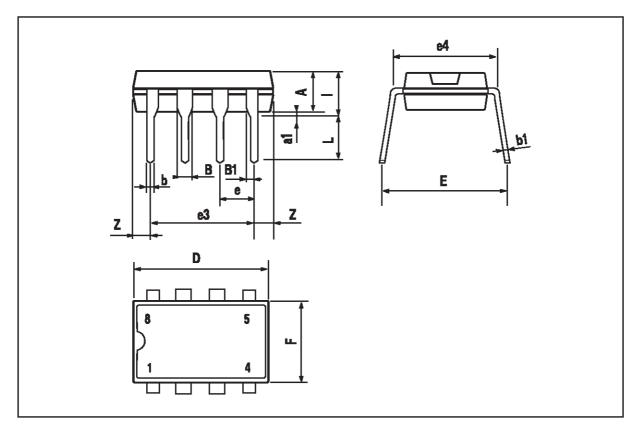


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DIM.		mm			inch	
Dilli.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А		3.32			0.131	
a1	0.51			0.020		
В	1.15		1.65	0.045		0.065
b	0.356		0.55	0.014		0.022
b1	0.204		0.304	0.008		0.012
D			10.92			0.430
Е	7.95		9.75	0.313		0.384
е		2.54			0.100	
еЗ		7.62			0.300	
e4		7.62			0.300	
F			6.6			0.260
I			5.08			0.200
L	3.18		3.81	0.125		0.150
Z			1.52			0.060

OUTLINE AND MECHANICAL DATA





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